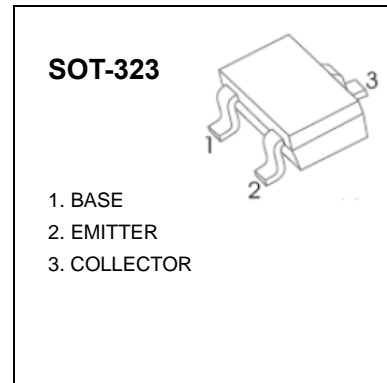


## SOT-323 Plastic-Encapsulate Transistors

**BC846W** TRANSISTOR (NPN)  
**BC847W**  
**BC848W**



### FEATURES

- Ideally suited for automatic insertion
- For Switching and AF Amplifier Applications

### MAXIMUM RATINGS (T<sub>a</sub>=25°C unless otherwise noted)

Symbol	Parameter		Value	Unit
<b>V<sub>CBO</sub></b>	Collector-Base Voltage	BC846W	80	V
		BC847W	50	
		BC848W	30	
<b>V<sub>CEO</sub></b>	Collector-Emitter Voltage	BC846W	65	V
		BC847W	45	
		BC848W	30	
<b>V<sub>EBO</sub></b>	Emitter-Base Voltage	BC846W	6	V
		BC847W	6	
		BC848W	5	
<b>I<sub>C</sub></b>	Collector Current –Continuous		0.1	A
<b>P<sub>C</sub></b>	Collector Power Dissipation		150	mW
<b>R<sub>JA</sub></b>	Thermal Resistance From Junction To Ambient		833	°C/W
<b>T<sub>J</sub></b>	Junction Temperature		150	°C
<b>T<sub>stg</sub></b>	Storage Temperature		-55-150	°C

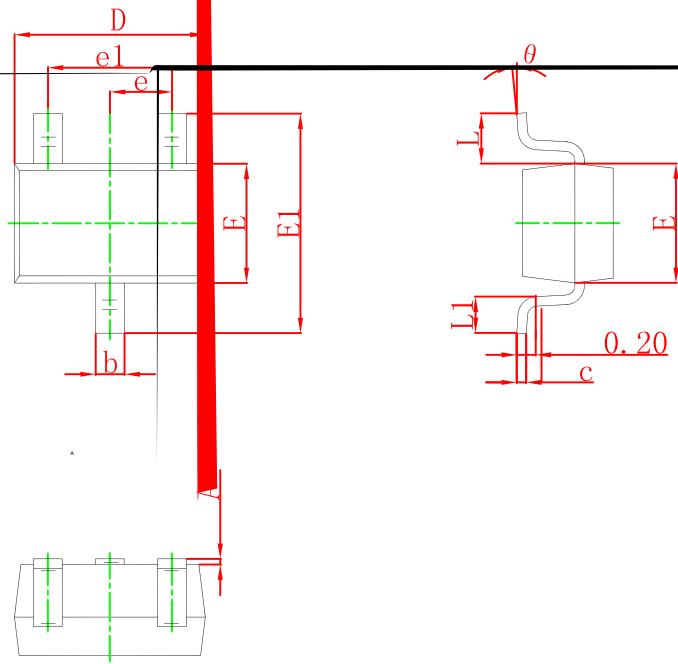
### DEVICE MARKING

BC846AW=1A; BC846BW=1B;  
 BC847AW=1E; BC847BW=1F; BC847CW=1G;  
 BC848AW=1J; BC848BW=1K; BC848CW=1L

**ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C unless otherwise specified)**

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	BC846W	$I_C = 10\mu A, I_E = 0$	80			V
	BC847W		50			
	BC848W		30			
Collector-emitter breakdown voltage	BC846W	$I_C = 10mA, I_B = 0$	65			V
	BC847W		45			
	BC848W		30			
Emitter-base breakdown voltage	BC846W	$I_E = 1\mu A, I_C = 0$	6			V
	BC847W		6			
	BC848W		5			
Collector Cutoff Current	$I_{CBO}$	$V_{CB} = 30V$			15	nA
DC current gain	BC846AW,847AW,848AW	$V_{CE} = 5V, I_C = 10\mu A$		90		
	BC846BW,847BW,848BW			150		
	BC847CW,BC848CW			270		
	BC846AW,847AW,848AW	$V_{CE} = 5V, I_C = 2mA$	110		220	
	BC846BW,847BW,848BW		200		450	
	BC847CW,BC848CW		420		800	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 10mA, I_B = 0.5mA$ $I_C = 100mA, I_B = 5mA$			0.25 0.6	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = 10mA, I_B = 0.5mA$ $I_C = 100mA, I_B = 5mA$		0.7 0.9		V
Base-emitter voltage	$V_{BE(on)}$	$V_{CE} = 5V, I_C = 2mA$ $V_{CE} = 5V, I_C = 10mA$	580	660	700 770	mV
Transition frequency	$f_T$	$V_{CE} = 5V, I_C = 10mA$ $f = 100MHz$	100			MHz
Collector output capacitance	$C_{ob}$	$V_{CB} = 10V, f = 1MHz$			4.5	pF
Noise figure	BC846AW,847AW,848AW	$V_{CE} = 5V, I_C = 0.2mA,$ $f = 1KHz, R_S = 2K\Omega$ $BW = 200Hz$			F€	dB
	BC846BW,847BW,848BW				10	
	BC847CW,BC848CW				4	





### NOTICE

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